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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR **N0300N**

# N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

### **DESCRIPTION**

The N0300N is a switching device which can be driven directly by a 4.5 V power source.

The device features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

### **FEATURES**

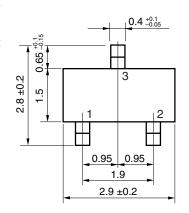
- 4.5 V drive available
- · Low on-state resistance

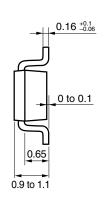
 $R_{DS(on)1}$  = 50 m $\Omega$  MAX. (V<sub>GS</sub> = 10 V, I<sub>D</sub> = 2.0 A)

 $R_{DS(on)2} = 83 \text{ m}\Omega \text{ MAX.} \text{ (Vgs = 4.5 V, ID = 2.0 A)}$ 

• Built-in gate protection diode

# PACKAGE DRAWING (Unit: mm)





- 1. Gate
- 2. Source
- 3. Drain

### ORDERING INFORMATION

PART NUMBER	PACKAGE
N0300N-T1B-AT Note	SC-96 (Mini Mold Thin Type)

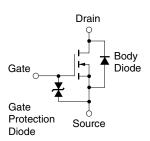
Note Pb-free (This product does not contain Pb in the external electrode and other parts.)

Marking: XY

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ )

VDSS	30	V
Vgss	±20	V
ID(DC)	±4.5	Α
I <sub>D(pulse)</sub>	±18	Α
P <sub>T1</sub>	0.2	W
P <sub>T2</sub>	1.25	W
Tch	150	°C
Tstg	-55 to +150	°C
	VGSS ID(DC) ID(pulse) PT1 PT2 Tch	VGSS ±20 ID(DC) ±4.5 ID(pulse) ±18 PT1 0.2 PT2 1.25 Tch 150

### **EQUIVALENT CIRCUIT**



**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

2. Mounted on FR-4 board of 50 mm x 50 mm x 1.6 mmt,  $t \le 5$  sec

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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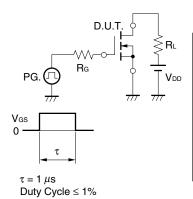


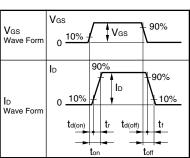
# **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Inss	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			1	μΑ
Gate Leakage Current	Igss	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μΑ
Gate to Source Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.0 mA	1.0		2.5	V
Forward Transfer Admittance Note	<b>y</b> fs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 2.0 A	1.0			S
Drain to Source On-state Resistance Note	RDS(on)1	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 2.0 A		38	50	mΩ
	RDS(on)2	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 2.0 A		48	83	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V,		350		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V,		65		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		30		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 15 V, I <sub>D</sub> = 2.0 A,		6.5		ns
Rise Time	tr	V <sub>GS</sub> = 10 V,		3.0		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 6 Ω		16.5		ns
Fall Time	tf			3.0		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 24 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 4.5 A		7.4		nC
Body Diode Forward Voltage Note	V <sub>F(S-D)</sub>	I <sub>F</sub> = 4.5 A, V <sub>GS</sub> = 0 V		0.9		V

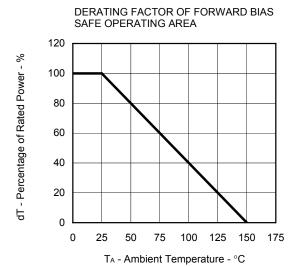
Note Pulsed

# **TEST CIRCUIT SWITCHING TIME**

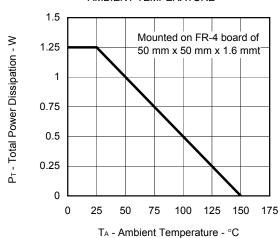




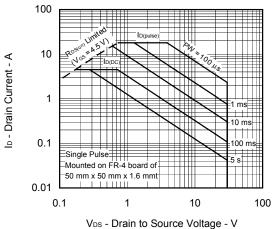
# TYPICAL CHARACTERISTICS (TA = 25°C)



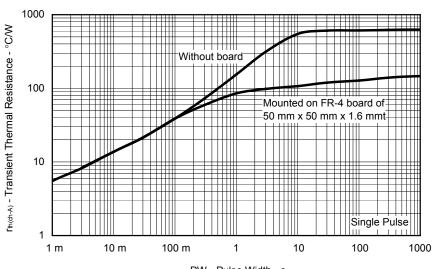
# TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



### FORWARD BIAS SAFE OPERATING AREA







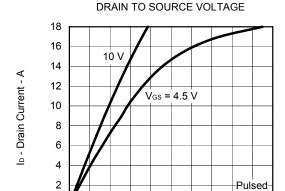
PW - Pulse Width - s

0

Ves(off) - Gate to Source Cut-off Voltage - V

0

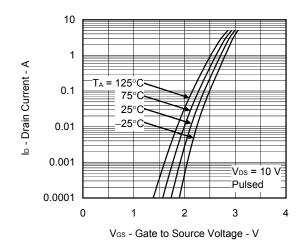
0.4



8.0

DRAIN CURRENT vs.

#### FORWARD TRANSFER CHARACTERISTICS



GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

VDS - Drain to Source Voltage - V

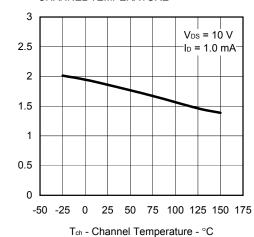
1.2

1.6

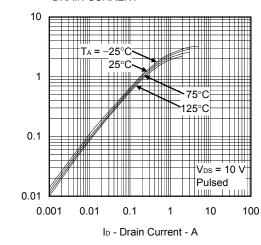
2

l y<sub>18</sub> | - Forward Transfer Admittance -

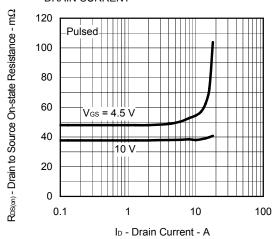
R<sub>DS(m)</sub> - Drain to Source On-state Resistance - mΩ



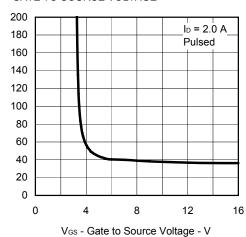
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

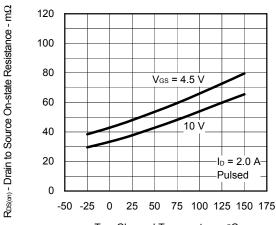


DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



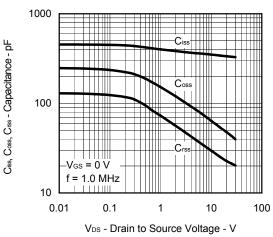
td(on), tr, td(off), tr - Switching Time - ns

# DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

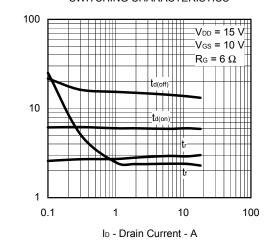


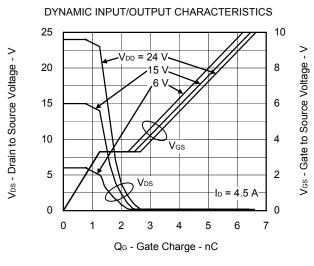
## T<sub>ch</sub> - Channel Temperature - °C

# CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

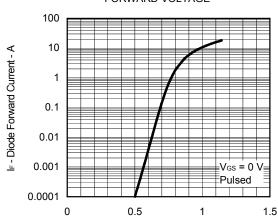


SWITCHING CHARACTERISTICS





SOURCE TO DRAIN DIODE FORWARD VOLTAGE



 $V_{\text{F(S-D)}}$  - Source to Drain Voltage - V

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